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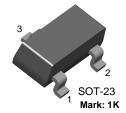
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### **MMBT6428**

# **NPN General Purpose Amplifier**

- This device designed for general pupose amplifier applications at collector currents to 300mA
- Sourced from process 10.



1. Base 2. Emitter 3. Collector

### **Absolute Maximum Ratings\*** T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V
V <sub>CBO</sub>	Collector-Base Voltage	60	V
I <sub>C</sub>	Collector Current - Continuous	500	mA
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES

1) These ratings are based on a maximum junction temperature of 150 degrees C.

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charact	eristics		•		•
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage *	$I_C = 1.0 \text{mA}, I_B = 0$	50		V
V <sub>(BR)CBO</sub>	Collector-Base BreakdownVoltage	$I_C = 100\mu A, I_E = 0$	60		V
I <sub>CEO</sub>	Collector Cut-off Current	$V_{CE} = 30V, I_{B} = 0$		0.1	μΑ
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 30V, I_{E} = 0$		10	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 5.0V, I_B = 0$		10	nA
On Charact	eristics		•		•
h <sub>FE</sub>	DC Current Gain	$\begin{aligned} &V_{CE} = 5.0 \text{V, I}_{C} = 10 \mu\text{A} \\ &V_{CE} = 5.0 \text{V, I}_{C} = 100 \mu\text{A} \\ &V_{CE} = 5.0 \text{V, I}_{C} = 1.0 \text{mA} \\ &V_{CE} = 5.0 \text{V, I}_{C} = 10 \text{mA} \end{aligned}$	250 250 250 250	650	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 10$ mA, $I_B = 0.5$ mA $I_C = 100$ mA, $I_B = 5.0$ mA		0.2 0.6	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = 5.0V, I_{C} = 1.0mA$	0.56	0.66	V
Small Signa	I Characteristics		•		•
f <sub>T</sub>	Current gain Bandwidth Product	$V_{CE} = 5.0V, I_{C} = 1.0mA,$ f = 100MHz	100	700	MHz
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 1.0MHz$		3.0	pF
C <sub>ibo</sub>	Input Capacitance	$V_{EB} = 0.5V, I_{C} = 0, f = 1.0MHz$		8.0	pF

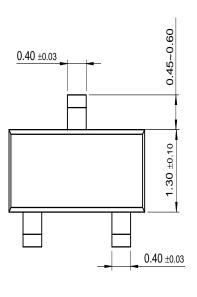
\*Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%

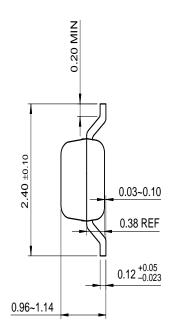
Thermal Characteristics T <sub>A</sub> =25°C unless otherwise noted			
Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C
$R_{ heta JC}$	Thermal Resistance, Junction to Case °C/M		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

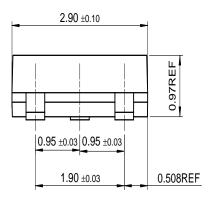
<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

# **Package Dimensions**

# **SOT-23**







Dimensions in Millimeters

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